

# BD675, BD675A, BD677, BD677A, BD679, BD679A, BD681

BD681 is a Preferred Device

## Plastic Medium-Power Silicon NPN Darlington

This series of plastic, medium-power silicon NPN Darlington transistors can be used as output devices in complementary general-purpose amplifier applications.

### Features

- High DC Current Gain:  

$$h_{FE} = 750 \text{ (Min) @ } I_C$$

$$= 1.5 \text{ and } 2.0 \text{ Adc}$$
- Monolithic Construction
- BD675, 675A, 677, 677A, 679, 679A, 681 are complementary with BD676, 676A, 678, 678A, 680, 680A, 682
- BD677, 677A, 679, 679A are equivalent to MJE 800, 801, 802, 803
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BD675, A BD677, A BD679, A BD681	$V_{CEO}$	45 60 80 100	Vdc
Collector-Base Voltage BD675, A BD677, A BD679, A BD681	$V_{CBO}$	45 60 80 100	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current	$I_C$	4.0	Adc
Base Current	$I_B$	1.0	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	40 0.32	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{JC}$	3.13	$^\circ\text{C/W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

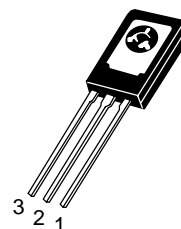
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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**4.0 AMPERES  
POWER TRANSISTORS  
NPN SILICON  
60, 80, 100 VOLTS, 40 WATTS**



TO-225AA  
CASE 77  
STYLE 1

### MARKING DIAGRAMS



BD6xx = Device Code  
 $x = 75, 77, 79, 81$   
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

# BD675, BD675A, BD677, BD677A, BD679, BD679A, BD681

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage, (Note 1) ( $I_C = 50\text{ mAdc}$ , $I_B = 0$ )	BD675, 675A BD677, 677A BD679, 679A BD681	$BV_{CEO}$	45 60 80 100	– – – –	Vdc
Collector Cutoff Current ( $V_{CE} = \text{Half Rated } BV_{CEO}$ , $I_B = 0$ )		$I_{CEO}$	–	500	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CB} = \text{Rated } BV_{CEO}$ , $I_E = 0$ ) ( $V_{CB} = \text{Rated } BV_{CEO}$ , $I_E = 0$ , $T_C = 100^\circ\text{C}$ )		$I_{CBO}$	– –	0.2 2.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )		$I_{EBO}$	–	2.0	mAdc

### ON CHARACTERISTICS

DC Current Gain, (Note 1) ( $I_C = 1.5\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ ) ( $I_C = 2.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )	BD675, 677, 679, 681 BD675A, 677A, 679A	$h_{FE}$	750 750	– –	–
Collector–Emitter Saturation Voltage, (Note 1) ( $I_C = 1.5\text{ Adc}$ , $I_B = 30\text{ mAdc}$ ) ( $I_C = 2.0\text{ Adc}$ , $I_B = 40\text{ mAdc}$ )	BD677, 679, 681 BD675A, 677A, 679A	$V_{CE(sat)}$	– –	2.5 2.8	Vdc
Base–Emitter On Voltage, (Note 1) ( $I_C = 1.5\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ ) ( $I_C = 2.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )	BD677, 679, 681 BD675A, 677A, 679A	$V_{BE(on)}$	– –	2.5 2.5	Vdc

### DYNAMIC CHARACTERISTICS

Small Signal Current Gain ( $I_C = 1.5\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ , $f = 1.0\text{ MHz}$ )	$h_{fe}$	1.0	–	–
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1. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

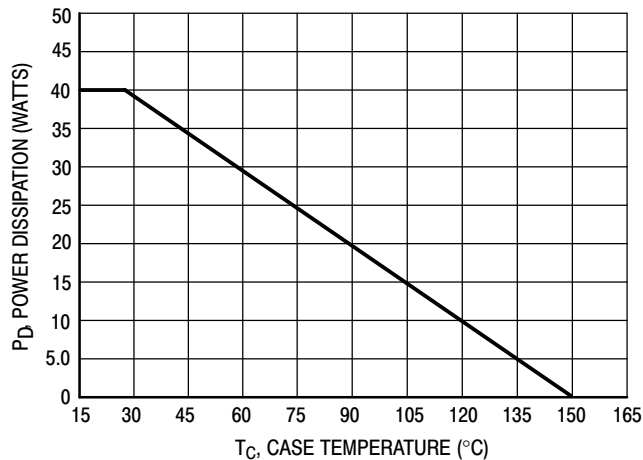


Figure 1. Power Temperature Derating

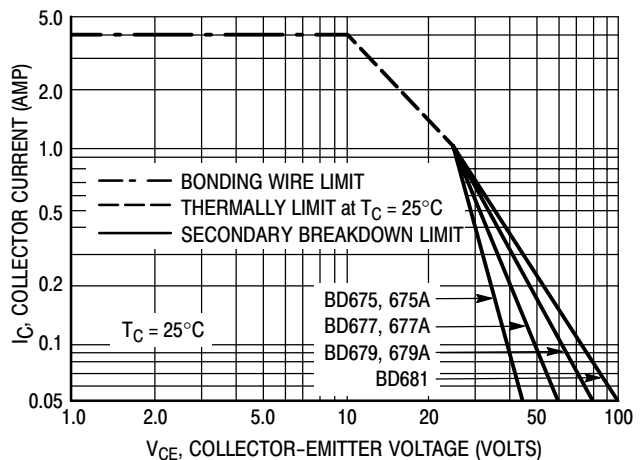


Figure 2. DC Safe Operating Area

There are two limitations on the power handling ability of a transistor average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

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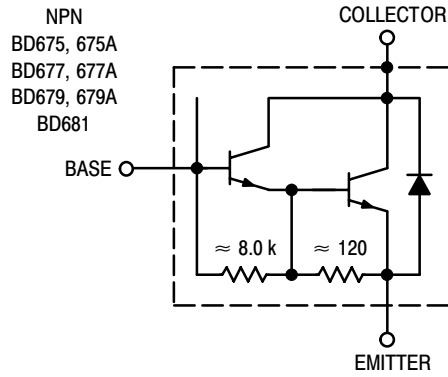


Figure 3. Darlington Circuit Schematic

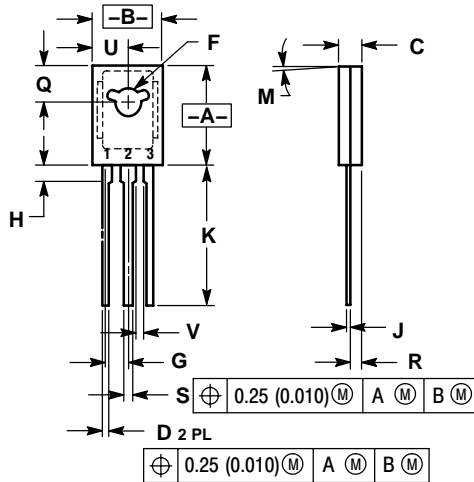
## ORDERING INFORMATION

Device	Package	Shipping
BD675	TO-225AA	500 Units / Box
BD675G	TO-225AA (Pb-Free)	500 Units / Box
BD675A	TO-225AA	500 Units / Box
BD675AG	TO-225AA (Pb-Free)	500 Units / Box
BD677	TO-225AA	500 Units / Box
BD677G	TO-225AA (Pb-Free)	500 Units / Box
BD677A	TO-225AA	500 Units / Box
BD677AG	TO-225AA (Pb-Free)	500 Units / Box
BD679	TO-225AA	500 Units / Box
BD679G	TO-225AA (Pb-Free)	500 Units / Box
BD679A	TO-225AA	500 Units / Box
BD679AG	TO-225AA (Pb-Free)	500 Units / Box
BD681	TO-225AA	500 Units / Box
BD681G	TO-225AA (Pb-Free)	500 Units / Box

# BD675, BD675A, BD677, BD677A, BD679, BD679A, BD681

## PACKAGE DIMENSIONS

TO-225AA  
CASE 77-09  
ISSUE Z



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	---	1.02	---

### STYLE 1:

- PIN 1. EMITTER
- COLLECTOR
- BASE

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